Diode Semiconductor Device - Page 1 of 1



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| Inclosure Material: | |
|--|--|
| Glass | |
| Overall Length: | |
| 0.080 inches | |
| Terminal Length: | |
| 0.750 inches | |
| Overall Diameter: | |
| 0.085 inches | |
| Mounting Method: | |
| Terminal | |
| Features Provided: | |
| Hermetically sealed case | |
| Semiconductor Material: | |
| Silicon | |
| Voltage Rating In Volts Per Characteristic: | |
| 200.0 reverse voltage, peak | |
| Current Rating Per Characteristic: | |
| 2.00 amperes forward current, average absolute | |
| Maximum Operating Tempurature Per Measurement Point: | |
| 175.0 degrees celsius ambient air | |
| Precious Material And Location: | |
| Terminal surfaces silver | |
| Precious Material: | |
| Silver | |
| Terminal Type And Quantity: | |
| 2 turret | |
| Shelf Life: | |
| N/a | |
| Unit Of Measure: | |
| - | |
| Demilitarization: | |
| No | |
| Filg: | |
| A110a0 | |